

SKN0 THRU SKN2

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 40 Volts Forward Current - 3.0 Amperes

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

Mechanical Data

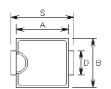
Case: SMC molded plastic body
Terminals: SMC leads, solderable per

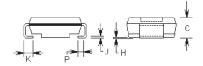
MIL-STD-750, method 2026

• Polarity: Color band denotes cathode end

Mounting Position: AnyWeight: 0.007 ounce, 0.25 gram

SMC





D IM E N S IO N S							
DIM	inches		m m		Note		
	M in .	Max.	M in.	Max.	Note		
A	0.260	0.280	6.60	7.11			
В	0.220	0.240	5.59	6.10			
С	0.075	0.095	1.90	2 .4 1			
D	0.115	0.121	2.92	3.07			
н	0.0020	0.0060	0.051	0.152			
J	0.006	0.012	0.15	0.30			
К	0.030	0.050	0.76	1.27			
P	0.020 REF		0.51 REF				
s	0.305	0.320	7.75	8.13			

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbols	SKN0	SKN1	SKN2	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	Volts
Non-repetitive peak reverse voltage	V _{RSM}	24	36	48	Volts
Maximum average forward rectified current at $\rm T_L$ =75 $^{\circ}\rm C$	I _(AV)	3.0		Amps	
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method) at $\rm T_L$ =75 $^{\circ}\rm C$	I _{FSM}	80.0			Amps
Maximum instantaneous forward voltage at 3.0A (Note 1) Maximum instantaneous forward voltage at 9.4A (Note 1)	$V_{\rm F}$	0.475 0.850	0.500 0.900	0.525 0.950	Volts Volts
$\begin{array}{ll} \mbox{Maximum instantaneous reverse current} & \mbox{$T_{\rm A}$=}25^{\circ}\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$	I _R	2.0 20.0			mA
Typical thermal resistance (Note 2)	R _{⊕JA} R _{⊕JL}	40.0 10.0			°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +125			°C

Notes

- (1) Pulse test: 300uS pulse width, 1% duty cycle
- (2) Mounted on P.C. Board with 14mm² (0.013mm thick) copper pad areas

RATINGS AND CHARACTERISTIC CURVES

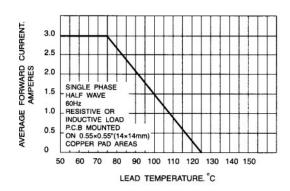


FIG. 1 - FORWARD CURRENT DERATING CURVE

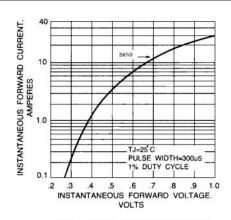


FIG. 2 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

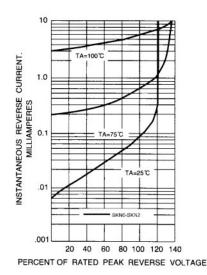


FIG. 3-TYPICAL REVERSE CHARACTERISTICS

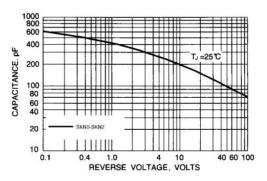


FIG. 4 - TYPICAL JUNCTION CAPACITANCE

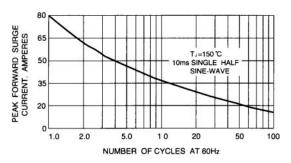


FIG. 5 – MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT